

# ZX5T951A

---

## 60V PNP LOW SATURATION MEDIUM POWER TRANSISTOR IN E-LINE

---

### SUMMARY

$BV_{CEO} = -60V$  ;  $R_{SAT} = 38m\Omega$  ;  $I_C = -3.5A$

### DESCRIPTION

Packaged in the E-line outline this new 5th generation low saturation 60V PNP transistor offers extremely low on state losses making it ideal for use in DC-DC circuits and various driving and power management functions.

### FEATURES

- 3.5 amps continuous current
- Up to 15 amps peak current
- Very low saturation voltages
- Excellent gain up to 10 amps

### APPLICATIONS

- DC - DC converters
- MOSFET gate drivers
- Power switches
- Motor control

### ORDERING INFORMATION

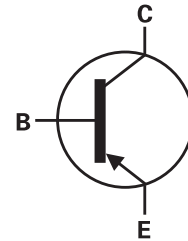
DEVICE	QUANTITY PER REEL
ZX5T951ASTOA	2000 units / reel
ZX5T951ASTZ	2000 units / carton

### DEVICE MARKING

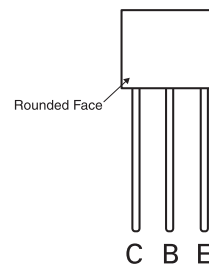
- X5T951



E-line



### PINOUT



TOP VIEW

# ZX5T951A

## ABSOLUTE MAXIMUM RATINGS

PARAMETER	SYMBOL	LIMIT	UNIT
Collector-base voltage	$BV_{CBO}$	-100	V
Collector-emitter voltage	$BV_{CEO}$	-60	V
Emitter-base voltage	$BV_{EBO}$	-7	V
Continuous collector current <sup>(a)</sup>	$I_C$	-3.5	A
Peak pulse current	$I_{CM}$	-15	A
Practical power dissipation at $T_A = 25^\circ\text{C}$ <sup>(a)</sup>	$P_D$	1.0	W
Linear derating factor		8	mW/ $^\circ\text{C}$
Power dissipation at $T_A = 25^\circ\text{C}$ <sup>(b)</sup>	$P_D$	0.71	W
Linear derating factor		5.7	mW/ $^\circ\text{C}$
Operating and storage temperature range	$T_j, T_{stg}$	-55 to 150	$^\circ\text{C}$

## THERMAL RESISTANCE

PARAMETER	SYMBOL	VALUE	UNIT
Junction to ambient <sup>(a)</sup>	$R_{\theta JA}$	125	$^\circ\text{C}/\text{W}$
Junction to ambient <sup>(b)</sup>	$R_{\theta JA}$	175	$^\circ\text{C}/\text{W}$

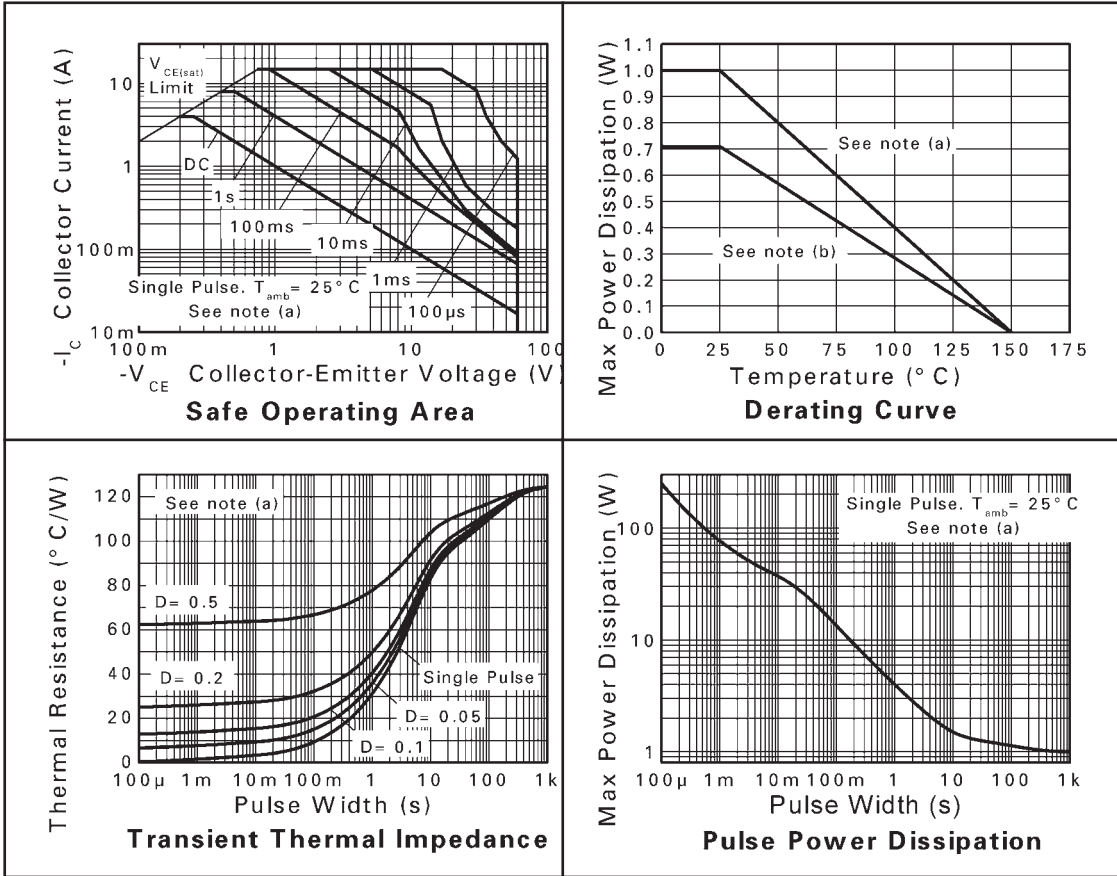
### NOTES

(a) For a device through hole mounted on 25mm x 25mm x 1.6mm FR4 PCB with high coverage of single sided 1oz copper, in still air conditions. Collector lead length to solder point 4mm.

(b) For a device mounted in a socket in still air conditions. Collector lead length 10mm.

# ZX5T951A

## CHARACTERISTICS



# ZX5T951A

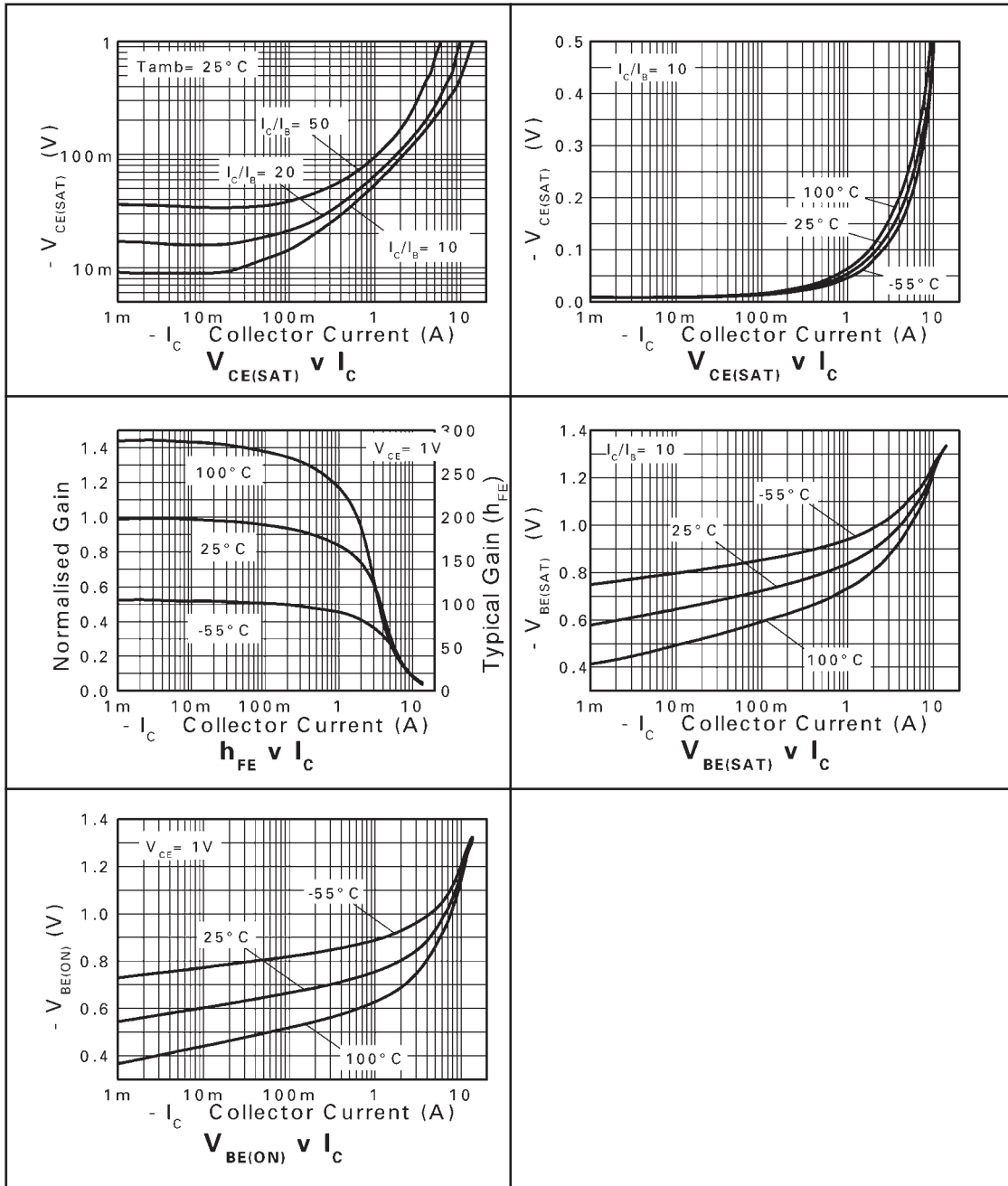
## ELECTRICAL CHARACTERISTICS (at $T_{amb} = 25^{\circ}\text{C}$ unless otherwise stated)

PARAMETER	SYMBOL	MIN.	TYP.	MAX.	UNIT	CONDITIONS
Collector-base breakdown voltage	$BV_{CBO}$	-100	-120		V	$I_C = -100\mu\text{A}$
Collector-emitter breakdown voltage	$BV_{CER}$	-100	-120		V	$I_C = -1\mu\text{A}$ , $R_B \leq 1\text{k}\Omega$
Collector-emitter breakdown voltage	$BV_{CEO}$	-60	-80		V	$I_C = -10\text{mA}^*$
Emitter-base breakdown voltage	$BV_{EBO}$	-7	-8.1		V	$I_E = -100\mu\text{A}$
Collector cut-off current	$I_{CBO}$		<1	-20 -0.5	nA $\mu\text{A}$	$V_{CB} = -80\text{V}$ $V_{CB} = -80\text{V}$ , $T_{amb} = 100^{\circ}\text{C}$
Collector cut-off current	$I_{CER}$ $R \leq 1\text{k}\Omega$		<1	-20 -0.5	nA $\mu\text{A}$	$V_{CB} = -80\text{V}$ $V_{CB} = -80\text{V}$ , $T_{amb} = 100^{\circ}\text{C}$
Emitter cut-off current	$I_{EBO}$		<1	-10	nA	$V_{EB} = -6\text{V}$
Collector-emitter saturation voltage	$V_{CE(SAT)}$		-14 -50 -80 -145	-20 -65 -115 -210	mV mV mV mV	$I_C = -0.1\text{A}$ , $I_B = -10\text{mA}^*$ $I_C = -1\text{A}$ , $I_B = -100\text{mA}^*$ $I_C = -2\text{A}$ , $I_B = -200\text{mA}^*$ $I_C = -4\text{A}$ , $I_B = -400\text{mA}^*$
Base-emitter saturation voltage	$V_{BE(SAT)}$		-960	-1060	mV	$I_C = -4\text{A}$ , $I_B = -400\text{mA}^*$
Base-emitter turn-on voltage	$V_{BE(ON)}$		-850	-960	mV	$I_C = -4\text{A}$ , $V_{CE} = -1\text{V}^*$
Static forward current transfer ratio	$h_{FE}$	100 100 65 10	250 200 120 25	300		$I_C = -10\text{mA}$ , $V_{CE} = -1\text{V}^*$ $I_C = -1\text{A}$ , $V_{CE} = -1\text{V}^*$ $I_C = -4\text{A}$ , $V_{CE} = -1\text{V}^*$ $I_C = -10\text{A}$ , $V_{CE} = -1\text{V}^*$
Transition frequency	$f_T$		120		MHz	$I_C = -100\text{mA}$ , $V_{CE} = -10\text{V}$ $f = 50\text{MHz}$
Output capacitance	$C_{OBO}$		48		pF	$V_{CB} = -10\text{V}$ , $f = 1\text{MHz}^*$
Switching times	$t_{ON}$ $t_{OFF}$		39 370		ns	$I_C = -1\text{A}$ , $V_{CC} = -10\text{V}$ , $I_{B1} = I_{B2} = -100\text{mA}$

\* Measured under pulsed conditions. Pulse width  $\leq 300\mu\text{s}$ ; duty cycle  $\leq 2\%$ .

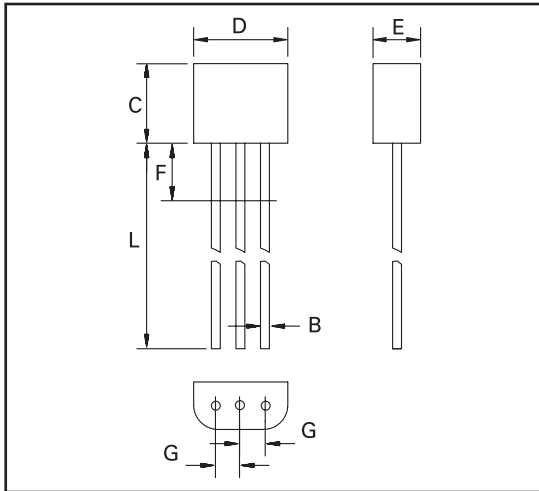
# ZX5T951A

## TYPICAL CHARACTERISTICS



# ZX5T951A

## PACKAGE OUTLINE



Controlling dimensions are in millimeters. Approximate conversions are given in inches

## PACKAGE DIMENSIONS

DIM	Millimeters		Inches	
	Min	Max	Min	Max
A	0.41	0.495	0.016	0.0195
B	0.41	0.495	0.016	0.0195
C	3.61	4.01	0.142	0.158
D	4.37	4.77	0.172	0.188
E	2.16	2.41	0.085	0.095
F	—	2.50	—	0.098
G	1.27 NOM		0.050 NOM	
L	13.00	13.97	0.512	0.550

© Zetex plc 2003

### Europe

Zetex plc  
Fields New Road  
Chadderton  
Oldham, OL9 8NP  
United Kingdom  
Telephone: (44) 161 622 4444  
Fax: (44) 161 622 4446  
hq@zetex.com

Zetex GmbH  
Streitfeldstraße 19  
D-81673 München  
Germany  
Telephone: (49) 89 45 49 49 0  
Fax: (49) 89 45 49 49 49  
europe.sales@zetex.com

### Americas

Zetex Inc  
700 Veterans Memorial Hwy  
Hauppauge, NY 11788  
USA  
Telephone: (1) 631 360 2222  
Fax: (1) 631 360 8222  
usa.sales@zetex.com

### Asia Pacific

Zetex (Asia) Ltd  
3701-04 Metroplaza Tower 1  
Hing Fong Road  
Kwai Fong  
Hong Kong  
Telephone: (852) 26100 611  
Fax: (852) 24250 494  
asia.sales@zetex.com

These offices are supported by agents and distributors in major countries world-wide.

This publication is issued to provide outline information only which (unless agreed by the Company in writing) may not be used, applied or reproduced for any purpose or form part of any order or contract or be regarded as a representation relating to the products or services concerned. The Company reserves the right to alter without notice the specification, design, price or conditions of supply of any product or service.

For the latest product information, log on to [www.zetex.com](http://www.zetex.com)



ISSUE 1 - JANUARY 2004